

SUBSTITUTE FORM PTO-1449 (MODIFIED)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY. DOCKET NO. IBM/319	SERIAL NO. 10/711,764
INFORMATION DISCLOSURE STATEMENT BY APPLICANT  (37 CFR 1.98(b))		(Use several sheets if necessary)		APPLICANT Toshiharu Furukawa et al.	
				FILING DATE October 4, 2004	GROUP 2823

## U.S. PATENT DOCUMENTS

EXAMINER INITIAL		PATENT NUMBER	ISSUE DATE	PATENTEE	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
C.A							
C.B							
C.C							
C.D							
C.E							
C.F							
C.G							
C.H							
C.I							
C.J							
C.K							

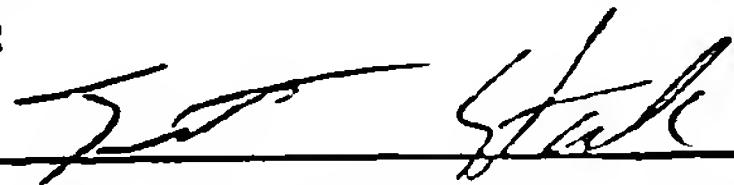
## FOREIGN PATENTS OR PUBLISHED FOREIGN PATENT APPLICATIONS

	DOCUMENT NUMBER	PUBLICATION DATE	COUNTRY OR PATENT OFFICE	CLASS	SUBCLASS	TRANSLATION (YES/NO)
C.L						
C.M						
C.N						
C.O						
C.P						
C.Q						

## OTHER DOCUMENTS (Including Author, Title, Date, Place of Publication)

SS	C.R	C-H. Kiang, "Growth of Larger-Diameter Single-Walled Carbon Nanotubes," J.Phys. Chem. A 2000, 104, 2454-2456
SS	C.S	E.Ploenjes, et al, "Single-Walled Carbon Nanotube Synthesis In CO Laser Pumped Monoxide Plasma". Oct 10, 2001
SS	C.T	Y.Mo, et al, "The growth mechanism of carbon nanotubes from thermal cracking of acetylene over nickel catalyst supported on alumina," 2001 Elsevier Science B.V

EXAMINER



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3/30/08

EXAMINER: Initial if citation considered, whether or not in conformance. Draw line through citation only if not in conformance and not considered.  
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JS	I.R	Z.Huang, Z.F.Ren., "Growth of highly oriented carbon nanotubes by plasma-enhanced hot filament chemical vapor deposition." Applied Physics Letters, Vol 73, Number 26, 28 December 1998
↓	I.S	G.S. Duesberg et al., Large-Scale Integration of Carbon Nanotubes Into Silicon Based Microelectronics, Proceedings of the SPIE, Bellingham, VA, Vol. 5118, May 21, 2003
JS	I.T	Furukawa et al., United States Patent Application Publication No. US 2005/0167655, Publication Date: August 4, 2005

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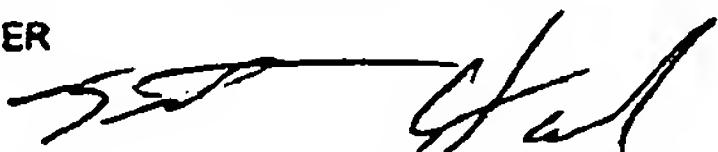
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JS	J.S	Won Bong Choi, et al, "Ultrahigh density nanotransistors by using selectively grown vertical carbon nanotubes", Applied Physics Letters, Volume 79, Number 22, 26 November 2001
JS	J.T	Bo Zheng, et al, "Efficient CVD Growth of Single-Walled Carbon Nanotubes on Surfaces Using Carbon Monoxide Precursor", Nano Letters, xxxx Vol.0, No 0 A.D. American Chemical Society revised June 26, 2002

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